

74ALVT16373

16-bit transparent D-type latch; 3-state

Rev. 5 — 14 July 2021

Product data sheet

1. General description

The 74ALVT16373 is a 16-bit D-type transparent latch with 3-state outputs. The device can be used as two 8-bit transparent latches or a single 16-bit transparent latch. The device features two latch enables (1LE and 2LE) and two output enables (1OE and 2OE), each controlling 8-bits. When nLE is HIGH, data at the inputs enter the latches. In this condition the latches are transparent, a latch output will change each time its corresponding D-input changes. When nLE is LOW the latches store the information that was present at the inputs a set-up time preceding the HIGH-to-LOW transition of nLE. A HIGH on nOE causes the outputs to assume a high-impedance OFF-state. Operation of the nOE input does not affect the state of the latches. Bus hold data inputs eliminate the need for external pull-up resistors to define unused inputs

2. Features and benefits

- Wide supply voltage range from 2.3 to 3.6 V
- Overvoltage tolerant inputs to 5.5 V
- BiCMOS high speed and output drive
- 16-bit transparent latch
- 5 V I/O compatible
- 3-state buffers
- Output capability: +64 mA/-32 mA
- Direct interface with TTL levels
- Input and output interface capability to systems at 5 V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power-up reset
- Power-up 3-State
- No bus current loading when output is tied to 5 V bus
- I_{OFF} circuitry provides partial Power-down mode operation
- Latch-up performance exceeds 500 mA per JESD 78 Class II Level B
- ESD protection:
 - MIL STD 883 method 3015: exceeds 2000 V
 - MM exceeds 200 V
- Specified from -40 °C to 85 °C

3. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74ALVT16373DGG	-40 °C to +85 °C	TSSOP48	plastic thin shrink small outline package; 48 leads; body width 6.1 mm	SOT362-1

4. Functional diagram

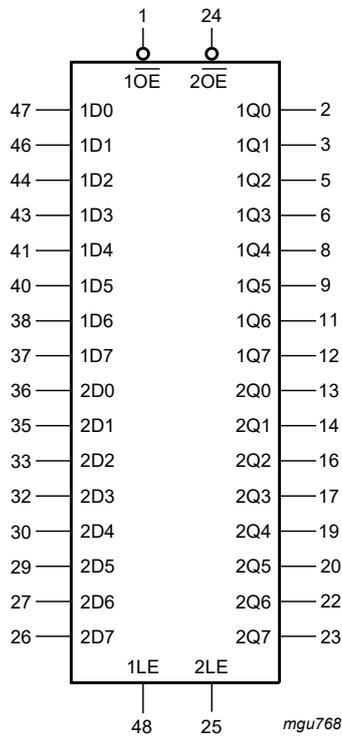


Fig. 1. Logic symbol

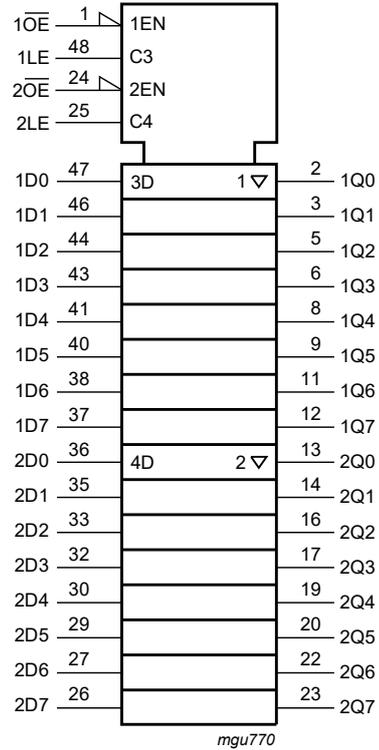


Fig. 2. IEC logic symbol

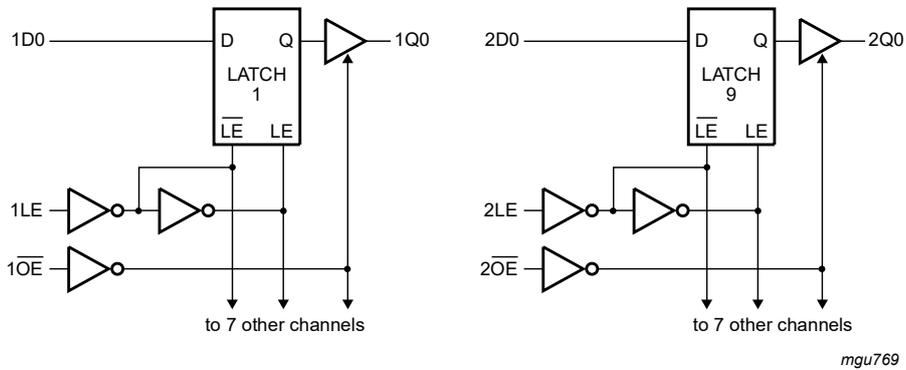


Fig. 3. Logic diagram

5. Pinning information

5.1. Pinning

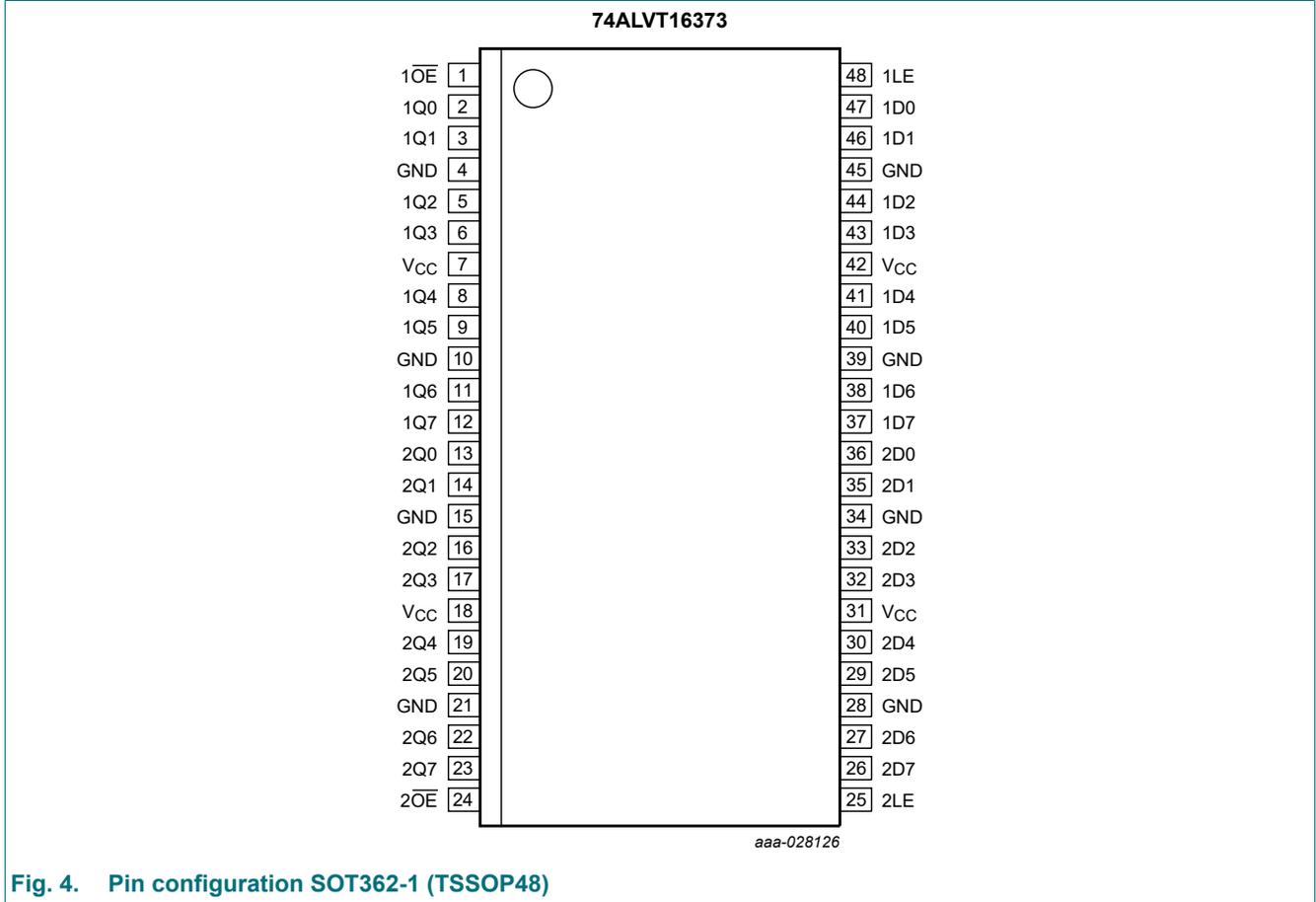


Fig. 4. Pin configuration SOT362-1 (TSSOP48)

5.2. Pin description

Table 2. Pin description

Symbol	Pin	Description
1D0, 1D1, 1D2, 1D3, 1D4, 1D5, 1D6, 1D7	47, 46, 44, 43, 41, 40, 38, 37	data inputs
2D0, 2D1, 2D2, 2D3, 2D4, 2D5, 2D6, 2D7	36, 35, 33, 32, 30, 29, 27, 26	data inputs
1Q0, 1Q1, 1Q2, 1Q3, 1Q4, 1Q5, 1Q6, 1Q7	2, 3, 5, 6, 8, 9, 11, 12	data outputs
2Q0, 2Q1, 2Q2, 2Q3, 2Q4, 2Q5, 2Q6, 2Q7	13, 14, 16, 17, 19, 20, 22, 23	data outputs
1OE, 2OE	1, 24	output enable inputs (active LOW)
1LE, 2LE	48, 25	latch enable inputs (active HIGH)
GND	4, 10, 15, 21, 28, 34, 39, 45	ground (0 V)
V _{CC}	7, 18, 31, 42	supply voltage

6. Functional description

Table 3. Function table

H = HIGH voltage level; h = HIGH voltage level one set-up time prior to the HIGH-to-LOW LE transition;

L = LOW voltage level; l = LOW voltage level one set-up time prior to the HIGH-to-LOW LE transition;

↓ = HIGH-to-LOW LE transition;

X = don't care; NC = No change; Z = high-impedance OFF-state.

Operating mode	Inputs			Internal latches	Outputs nQn
	nOE	nLE	nDn		
enable and read register (transparent mode)	L	H	L	L	L
	L	H	H	H	H
latch and read register	L	↓	l	L	L
	L	↓	h	H	H
Hold	L	L	X	NC	NC
Latch register and disable outputs	H	L	X	NC	Z
	H	H	nDn	nDn	Z

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
V _I	input voltage	[1]	-0.5	+7.0	V
V _O	output voltage	output in OFF-state or HIGH-state [1]	-0.5	+7.0	V
I _{IK}	input clamping current	V _I < 0 V	-50	-	mA
I _{OK}	output clamping current	V _O < 0 V	-50	-	mA
I _O	output current	output in LOW-state	-	128	mA
		output in HIGH-state	-64	-	mA
T _{stg}	storage temperature		-65	+150	°C
T _j	junction temperature	[2]	-	+150	°C

[1] The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

[2] The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	$V_{CC} = 2.5 V \pm 0.2 V$		$V_{CC} = 3.3 V \pm 0.3 V$		Unit
			Min	Max	Min	Max	
V_{CC}	supply voltage		2.3	2.7	3.0	3.6	V
V_I	input voltage		0	5.5	0	5.5	V
I_{OH}	HIGH-level output current		-	-8	-	-32	mA
I_{OL}	LOW-level output current	none	-	8	-	32	mA
		current duty cycle $\leq 50\%$; $f_i \geq 1$ kHz	-	24	-	64	mA
$\Delta t/\Delta V$	input transition rise and fall rate	outputs enabled	-	10	-	10	ns/V
T_{amb}	ambient temperature	free-air	-40	+85	-40	+85	$^{\circ}C$

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions; $T_{amb} = -40^{\circ}C$ to $+85^{\circ}C$; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
$V_{CC} = 2.5 V \pm 0.2 V$						
V_{IK}	input clamping voltage	$V_{CC} = 2.3 V$; $I_{IK} = -18$ mA	-	-0.85	-1.2	V
V_{IH}	HIGH-level input voltage		1.7	-	-	V
V_{IL}	LOW-level input voltage		-	-	0.7	V
V_{OH}	HIGH-level output voltage	$V_{CC} = 2.3 V$ to $2.7 V$; $I_O = -100$ μA	$V_{CC} - 0.2$	-	-	V
		$V_{CC} = 2.3 V$; $I_O = -8$ mA	1.8	-	-	V
V_{OL}	LOW-level output voltage	$V_{CC} = 2.3 V$; $I_O = 100$ μA	-	0.07	0.2	V
		$V_{CC} = 2.3 V$; $I_O = 24$ mA	-	0.3	0.5	V
$V_{OL(pu)}$	power-up LOW-level output voltage	$V_{CC} = 2.7 V$; $I_O = 1$ mA; $V_I = V_{CC}$ or GND [2]	-	-	0.55	V
I_I	input leakage current	all input pins [3]				
		$V_{CC} = 0 V$ or $2.7 V$; $V_I = 5.5 V$	-	0.1	10	μA
		control pins				
		$V_{CC} = 2.7 V$; $V_I = V_{CC}$ or GND	-	0.1	± 1	μA
		data pins; [3]				
		$V_{CC} = 2.7 V$; $V_I = V_{CC}$	-	0.1	1	μA
		$V_{CC} = 2.7 V$; $V_I = 0 V$	-	0.1	-5	μA
I_{OFF}	power-off leakage current	$V_{CC} = 0 V$; V_I or $V_O = 0 V$ to $4.5 V$	-	0.1	± 100	μA
I_{BHL}	bus hold LOW current	data inputs; $V_{CC} = 2.3 V$; $V_I = 0.7 V$ [4]	-	90	-	μA
I_{BHH}	bus hold HIGH current	data inputs; $V_{CC} = 2.3 V$; $V_I = 1.7 V$ [4]	-	-10	-	μA
I_{EX}	external current	output in HIGH-state when $V_O > V_{CC}$; $V_O = 5.5 V$; $V_{CC} = 2.3 V$	-	10	125	μA
$I_{O(pu/pd)}$	power-up/power-down output current	$V_{CC} \leq 1.2 V$; $V_O = 0.5 V$ to V_{CC} ; $V_I = GND$ or V_{CC} ; $n\overline{OE} = \text{don't care}$ [5]	-	1	100	μA

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
I _{OZ}	OFF-state output current	V _{CC} = 2.7 V; V _I = V _{IL} or V _{IH}				
		output HIGH: V _O = 2.3V	-	0.5	5	μA
		output LOW: V _O = 0.5 V	-	0.5	-5	μA
I _{CC}	supply current	V _{CC} = 2.7 V; V _I = GND or V _{CC} ; I _O = 0 A				
		outputs HIGH	-	0.04	0.1	mA
		outputs LOW	-	2.3	4.5	mA
		outputs disabled [6]	-	0.04	0.1	mA
ΔI _{CC}	additional supply current	per input pin; V _{CC} = 2.3 V to 2.7 V; one input at V _{CC} - 0.6 V; other inputs at V _{CC} or GND [7]	-	0.04	0.4	mA
C _I	input capacitance	V _I = 0 V or V _{CC}	-	3	-	pF
C _O	output capacitance	Outputs disabled; V _O = 0 V or 3 V	-	9	-	pF
V_{CC} = 3.3 V ± 0.3 V						
V _{IK}	input clamping voltage	V _{CC} = 3.0 V; I _{IK} = -18 mA	-	-0.85	-1.2	V
V _{IH}	HIGH-level input voltage		2.0	-	-	V
V _{IL}	LOW-level input voltage		-	-	0.8	V
V _{OH}	HIGH-level output voltage	V _{CC} = 3.3 V ± 0.3 V; I _O = -100 μA	V _{CC} - 0.2	V _{CC}	-	V
		V _{CC} = 3.0 V; I _O = -32 mA	2.0	2.3	-	V
V _{OL}	LOW-level output voltage	V _{CC} = 3.0 V; I _O = 100 μA	-	0.07	0.2	V
		V _{CC} = 3.0 V; I _O = 16 mA	-	0.25	0.4	V
		V _{CC} = 3.0 V; I _O = 32 mA	-	0.3	0.5	V
		V _{CC} = 3.0 V; I _O = 64 mA	-	0.4	0.55	V
V _{OL(pu)}	power-up LOW-level output voltage	V _{CC} = 3.6 V; I _O = 1 mA; V _I = V _{CC} or GND [2]	-	-	0.55	V
I _I	input leakage current	all input pins [3]				
		V _{CC} = 0 V or 3.6 V; V _I = 5.5 V	-	0.1	10	μA
		control pins				
		V _{CC} = 3.6 V; V _I = V _{CC} or GND	-	0.1	±1	μA
		data pins [3]				
		V _{CC} = 3.6 V; V _I = V _{CC}	-	0.5	1	μA
		V _{CC} = 3.6 V; V _I = 0 V	-	0.1	-5	μA
I _{OFF}	power-off leakage current	V _{CC} = 0 V; V _I or V _O = 0 V to 4.5 V	-	0.1	±100	μA
I _{BHL}	bus hold LOW current	data inputs; V _{CC} = 3 V; V _I = 0.8 V	75	130	-	μA
I _{BHH}	bus hold HIGH current	data inputs; V _{CC} = 3 V; V _I = 2.0 V	-75	-140	-	μA
I _{BHLO}	bus hold LOW overdrive current	data inputs; V _{CC} = 3.6 V; V _I = 0 V to 3.6 V [8]	500	-	-	μA
I _{BHHO}	bus hold HIGH overdrive current	data inputs; V _{CC} = 3.6 V; V _I = 0 V to 3.6 V [8]	-500	-	-	μA
I _{EX}	external current	output in HIGH-state when V _O > V _{CC} ; V _O = 5.5 V; V _{CC} = 3.0 V	-	10	125	μA
I _{O(pu/pd)}	power-up/power-down output current	V _{CC} ≤ 1.2 V; V _O = 0.5 V to V _{CC} ; V _I = GND or V _{CC} ; nOE = don't care [9]	-	1	±100	μA
I _{OZ}	OFF-state output current	V _{CC} = 3.6 V; V _I = V _{IL} or V _{IH}				
		output HIGH: V _O = 3.0V	-	0.5	5	μA
		output LOW: V _O = 0.5 V	-	0.5	-5	μA

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
I_{CC}	supply current	$V_{CC} = 3.6\text{ V}$; $V_I = \text{GND}$ or V_{CC} ; $I_O = 0\text{ A}$				
		outputs HIGH	-	0.04	0.1	mA
		outputs LOW	-	3.5	5	mA
		outputs disabled [6]	-	0.05	0.1	mA
ΔI_{CC}	additional supply current	per input pin; $V_{CC} = 3\text{ V}$ to 3.6 V ; one input at $V_{CC} - 0.6\text{ V}$; other inputs at V_{CC} or GND [7]	-	0.04	0.4	mA
C_I	input capacitance	$V_I = 0\text{ V}$ or V_{CC}	-	3	-	pF
C_O	output capacitance	output disabled; $V_O = 0\text{ V}$ or 3 V	-	9	-	pF

- [1] All typical values for $V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$ are measured at $V_{CC} = 2.5\text{ V}$ and $T_{amb} = 25\text{ }^\circ\text{C}$.
All typical values for $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$ are measured at $V_{CC} = 3.3\text{ V}$ and $T_{amb} = 25\text{ }^\circ\text{C}$.
- [2] For valid test results, data must not be loaded into the latches after applying power.
- [3] Unused pins at V_{CC} or GND.
- [4] Not guaranteed.
- [5] This parameter is valid for any V_{CC} between 0 V and 1.2 V with a transition time of up to 10 ms .
From $V_{CC} = 1.2\text{ V}$ to $V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$ a transition time of $100\text{ }\mu\text{s}$ is permitted. This parameter is valid for $T_{amb} = 25\text{ }^\circ\text{C}$ only.
- [6] I_{CC} with outputs disabled is measured with outputs pulled to V_{CC} or GND.
- [7] This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND.
- [8] This is the bus hold overdrive current required to force the input to the opposite logic state.
- [9] This parameter is valid for any V_{CC} between 0 V and 1.2 V with a transition time of up to 10 ms .
From $V_{CC} = 1.2\text{ V}$ to $V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$ a transition time of $100\text{ }\mu\text{s}$ is permitted. This parameter is valid for $T_{amb} = 25\text{ }^\circ\text{C}$ only.

10. Dynamic characteristics

Table 7. Dynamic characteristics

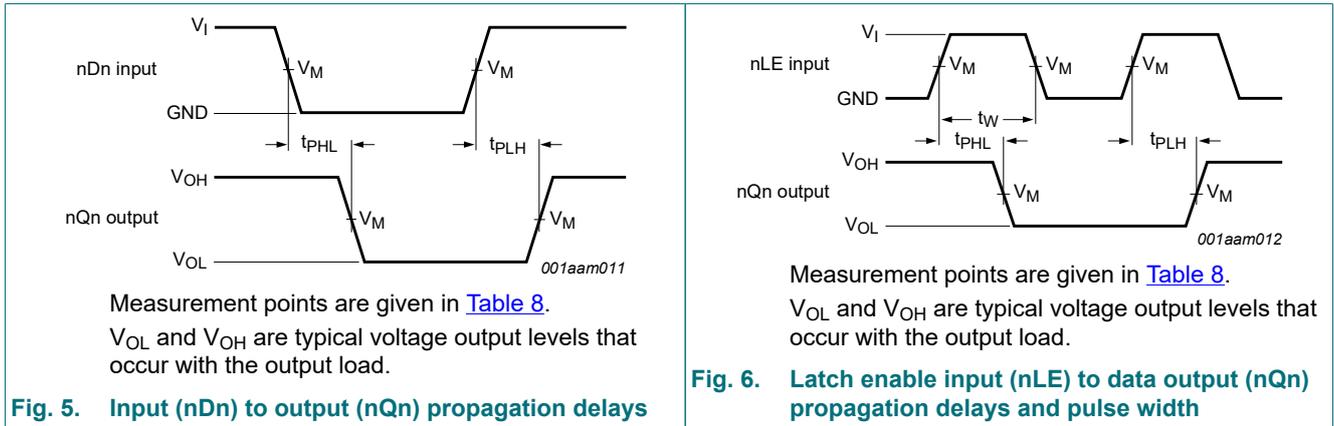
At recommended operating conditions; $T_{amb} = -40\text{ }^\circ\text{C}$ to $+85\text{ }^\circ\text{C}$; voltages are referenced to GND (ground = 0 V);
for test circuit see Fig. 9.

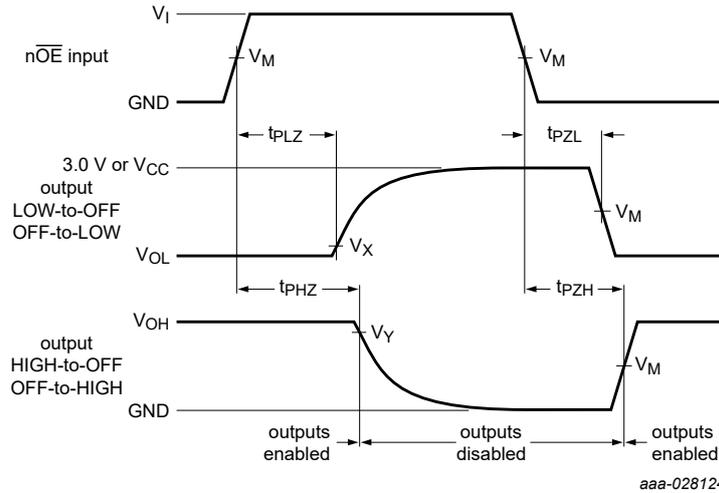
Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
$V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$						
t_{PLH}	LOW to HIGH propagation delay	nDn to nQn; see Fig. 5	1.0	2.0	3.2	ns
t_{PHL}	HIGH to LOW propagation delay	nDn to nQn; see Fig. 5	1.0	2.4	4.2	ns
t_{PLH}	LOW to HIGH propagation delay	nLE to nQn; see Fig. 6	1.5	2.6	4.2	ns
t_{PHL}	HIGH to LOW propagation delay	nLE to nQn; see Fig. 6	1.5	2.8	4.5	ns
t_{PZH}	OFF-state to HIGH propagation delay	\overline{nOE} to nQn; see Fig. 7	2.0	3.5	5.5	ns
t_{PZL}	OFF-state to LOW propagation delay	\overline{nOE} to nQn; see Fig. 7	1.5	2.6	4.7	ns
t_{PHZ}	HIGH to OFF-state propagation delay	\overline{nOE} to nQn; see Fig. 7	1.5	2.7	4.5	ns
t_{PLZ}	LOW to OFF-state propagation delay	\overline{nOE} to nQn; see Fig. 7	1.0	2.0	3.5	ns
$t_{su(H)}$	set-up time HIGH	nDn to nLE; see Fig. 8	0	-0.7	-	ns
$t_{su(L)}$	set-up time LOW	nDn to nLE; see Fig. 8	1.5	0.2	-	ns
$t_{h(H)}$	hold time HIGH	nDn to nLE; see Fig. 8	0.5	-0.2	-	ns
$t_{h(L)}$	hold time LOW	nDn to nLE; see Fig. 8	1.5	0.7	-	ns
t_{WH}	pulse width HIGH	nLE; see Fig. 6	1.5	-	-	ns

Symbol	Parameter	Conditions	Min	Typ[1]	Max	Unit
V_{CC} = 3.3 V ± 0.3 V						
t _{PLH}	LOW to HIGH propagation delay	nDn to nQn; see Fig. 5	0.5	1.6	2.5	ns
t _{PHL}	HIGH to LOW propagation delay	nDn to nQn; see Fig. 5	0.5	1.8	2.9	ns
t _{PLH}	LOW to HIGH propagation delay	nLE to nQn; see Fig. 6	1.0	2.0	3.1	ns
t _{PHL}	HIGH to LOW propagation delay	nLE to nQn; see Fig. 6	1.0	2.3	3.3	ns
t _{PZH}	OFF-state to HIGH propagation delay	n \overline{OE} to nQn; see Fig. 7	1.5	2.3	4.0	ns
t _{PZL}	OFF-state to LOW propagation delay	n \overline{OE} to nQn; see Fig. 7	1.0	1.9	3.1	ns
t _{PHZ}	HIGH to OFF-state propagation delay	n \overline{OE} to nQn; see Fig. 7	1.5	2.9	4.5	ns
t _{PLZ}	LOW to OFF-state propagation delay	n \overline{OE} to nQn; see Fig. 7	1.5	2.3	3.7	ns
t _{su(H)}	set-up time HIGH	nDn to nLE; see Fig. 8	0.5	-0.2	-	ns
t _{su(L)}	set-up time LOW	nDn to nLE; see Fig. 8	0.8	0.2	-	ns
t _{h(H)}	hold time HIGH	nDn to nLE; see Fig. 8	0.8	0	-	ns
t _{h(L)}	hold time LOW	nDn to nLE; see Fig. 8	1.0	0.2	-	ns
t _{WH}	pulse width HIGH	nLE; see Fig. 6	1.5	-	-	ns

[1] All typical values for V_{CC} = 2.5 V ± 0.2 V are measured at V_{CC} = 2.5 V and T_{amb} = 25 °C.
 All typical values for V_{CC} = 3.3 V ± 0.3 V are measured at V_{CC} = 3.3 V and T_{amb} = 25 °C.

10.1. Waveforms and test circuit

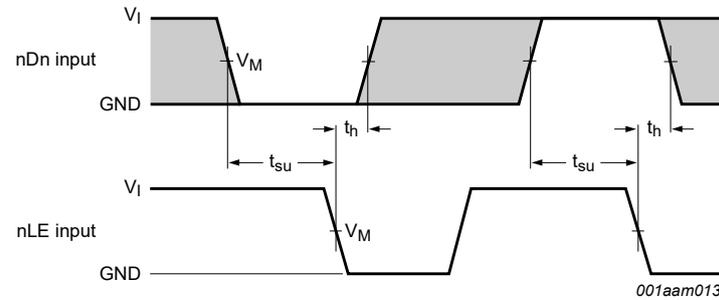




Measurement points are given in [Table 8](#).

V_{OL} and V_{OH} are typical voltage output levels that occur with the output load.

Fig. 7. OFF-state to HIGH or LOW and HIGH or LOW to OFF-state propagation delays



Measurement points are given in [Table 8](#).

Fig. 8. Input (nDn) to input (nLE) data set-up and hold times

Table 8. Measurement points

V_{CC}	Input		Output		
	V_I	V_M	V_M	V_X	V_Y
$V_{CC} \leq 2.7 \text{ V}$	V_{CC}	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	$V_{OL} + 0.15 \text{ V}$	$V_{OH} - 0.15 \text{ V}$
$V_{CC} \geq 3.0 \text{ V}$	3.0 V	1.5 V	1.5 V	$V_{OL} + 0.3 \text{ V}$	$V_{OH} - 0.3 \text{ V}$

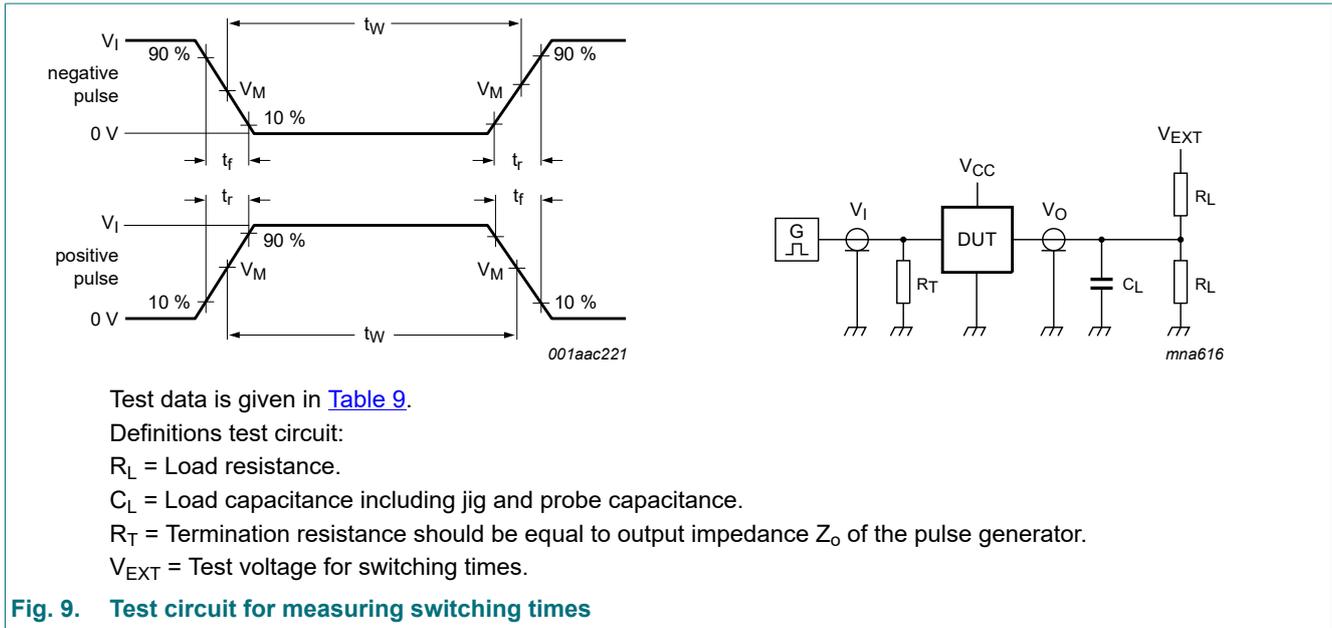


Table 9. Test data

Input				Load		V_{EXT}		
V_I	f_i	t_W	t_r, t_f	C_L	R_L	t_{PHZ}, t_{PZH}	t_{PLZ}, t_{PZL}	t_{PLH}, t_{PHL}
3.0 V or V_{CC} whichever is less	≤ 10 MHz	500 ns	≤ 2.5 ns	50 pF	500 Ω	GND	6 V or $V_{CC} \times 2$	open

11. Package outline

TSSOP48: plastic thin shrink small outline package; 48 leads; body width 6.1 mm

SOT362-1

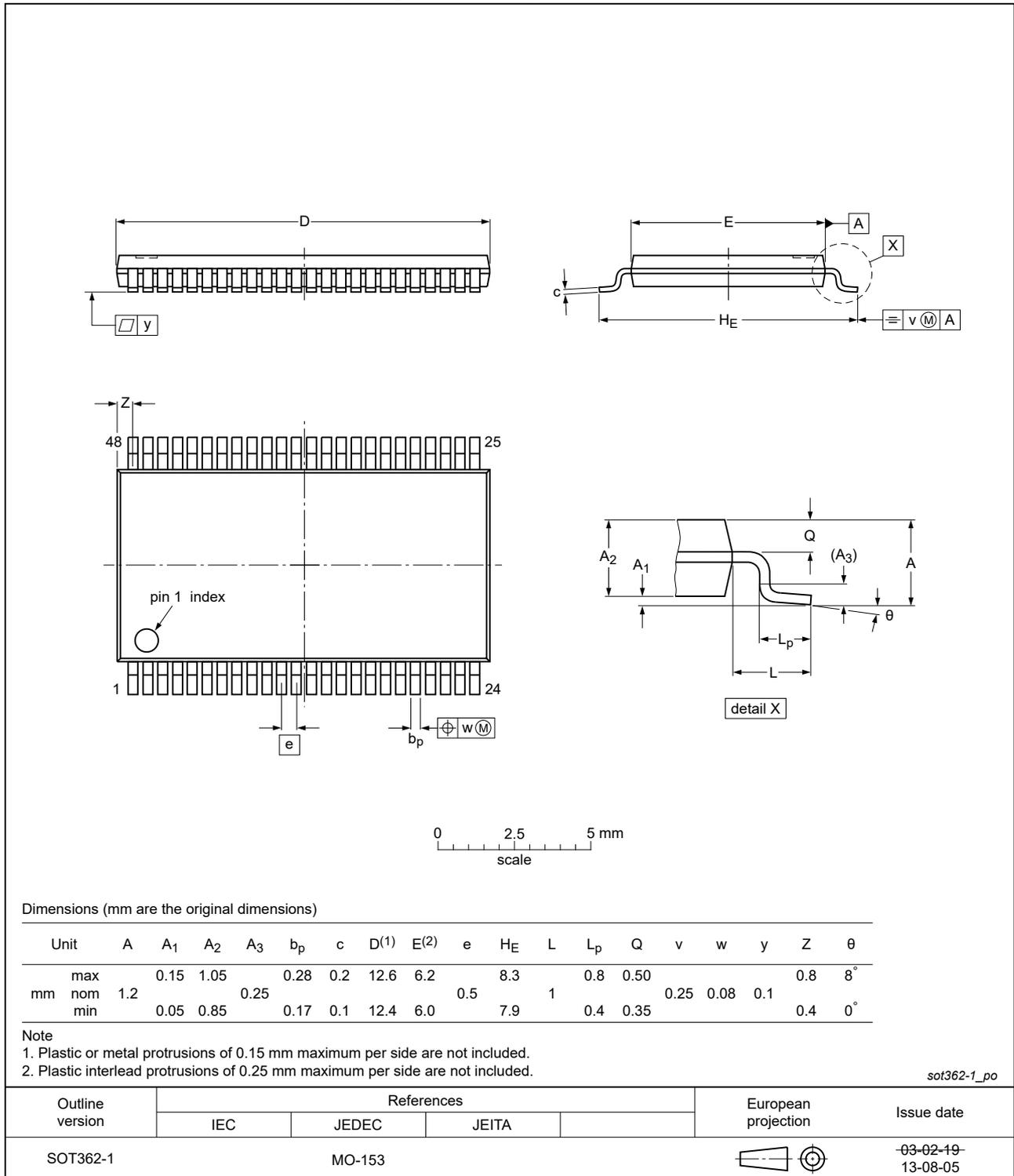


Fig. 10. Package outline SOT362-1 (TSSOP48)

12. Abbreviations

Table 10. Abbreviations

Acronym	Description
BiCMOS	Bipolar Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
MIL	Military
MM	Machine Model
TTL	Transistor-Transistor Logic

13. Revision history

Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74ALVT16373 v.5	20210714	Product data sheet	-	74ALVT16373 v.4
Modifications:	<ul style="list-style-type: none"> • Section 1 and Section 2 updated. • Type number 74ALVT16373DL (SOT370-1/SSOP48) removed. 			
74ALVT16373 v.4	20180202	Product data sheet	-	74ALVT16373 v.3
Modifications:	<ul style="list-style-type: none"> • The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. • Legal texts have been adapted to the new company name where appropriate. 			
74ALVT16373 v.3	19991018	Product specification	-	74ALVT16373 v.2
74ALVT16373 v.2	19980213	Product specification	-	74ALVT16373 v.1
74ALVT16373 v.1	19960529	Product specification	-	-

14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the internet at <https://www.nexperia.com>.

Definitions

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